

# **Device Modeling Report**

**COMPONENTS:**

**DIODE/ SCHOTTKY RECTIFIER / STANDARD**

**PART NUMBER: GSQ05A04B**

**MANUFACTURER: NIEC**

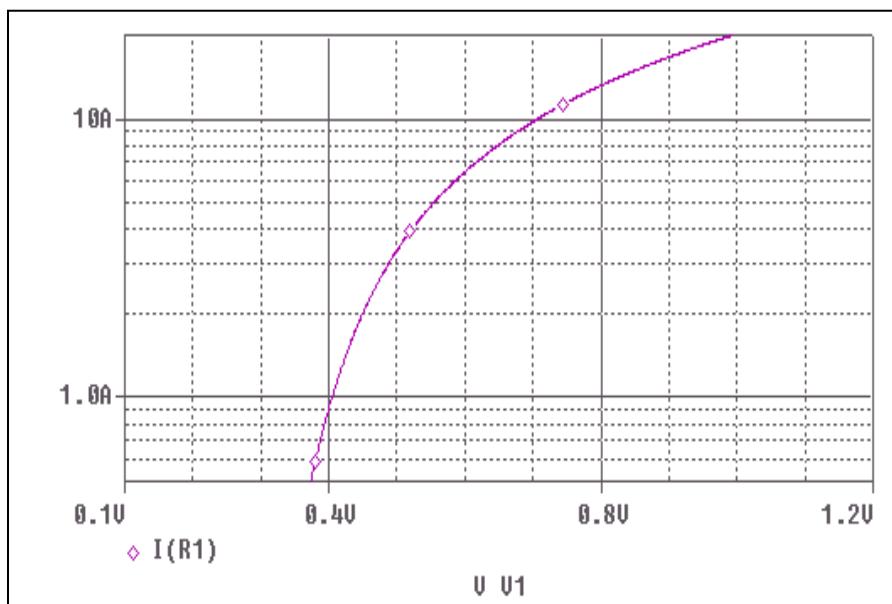


**Bee Technologies Inc.**

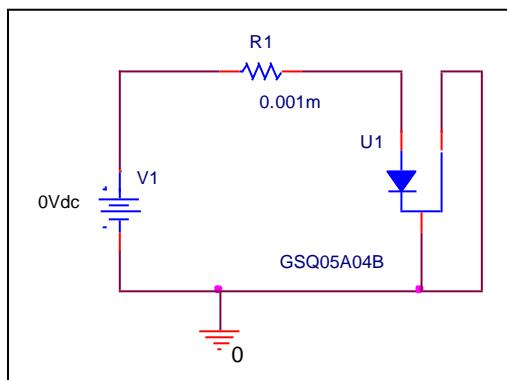
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

## Forward Current Characteristic

Circuit Simulation Result

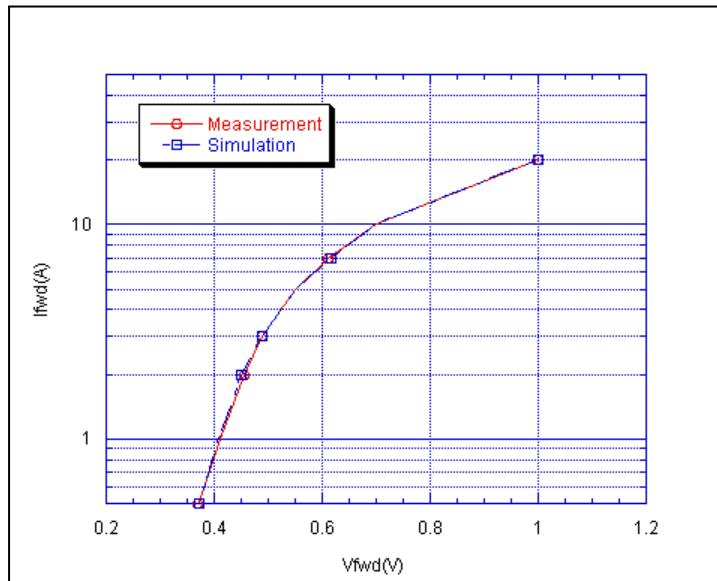


Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result

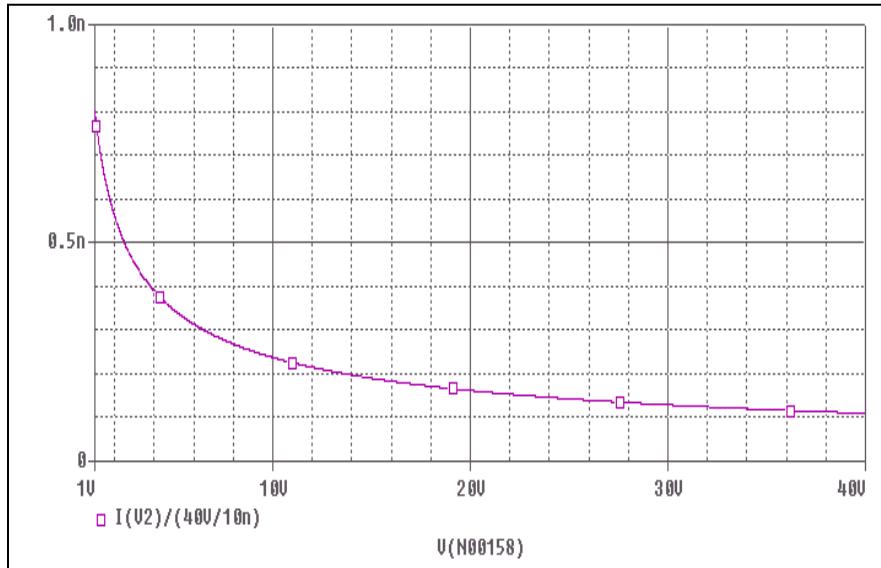


### Simulation Result

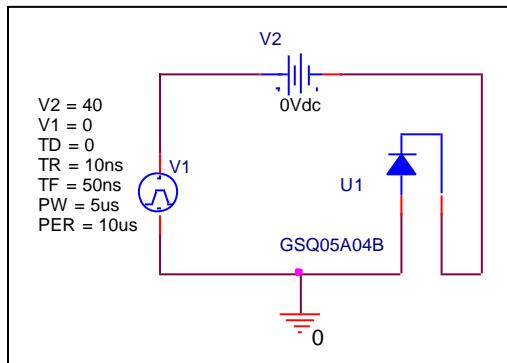
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
0.5	0.370	0.373	0.81
1	0.411	0.408	-0.73
2	0.456	0.450	-1.32
5	0.550	0.545	-0.91
10	0.700	0.698	-0.29
20	1.000	0.994	-0.60

## Junction Capacitance Characteristic

### Circuit Simulation Result

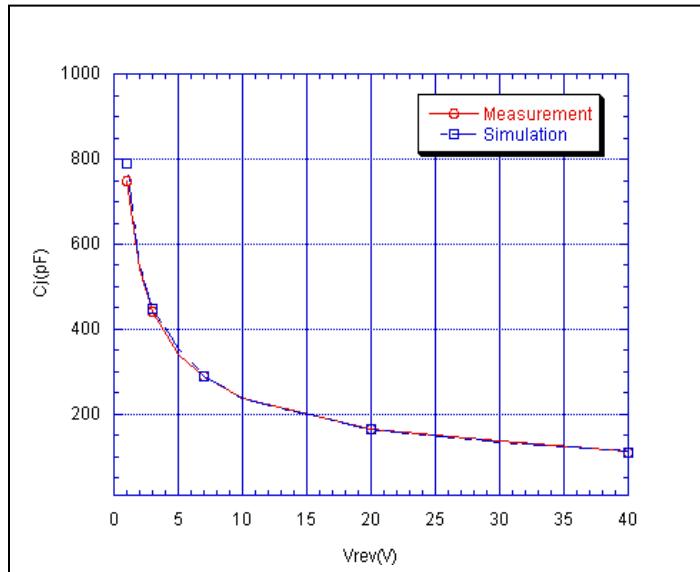


### Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result



### Simulation Result

Vrev(V)	Cj(pF) Measurement	Cj(pF) Simulation	%Error
1	760.000	789.000	3.82
2	540.000	553.000	2.41
5	344.000	356.000	3.49
10	239.000	238.000	-0.42
20	167.000	165.000	-1.20
40	112.000	110.000	-1.79